

SEP8506

GaAs Infrared Emitting Diode

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|---------------------------------|---------------------------------|------|------|-----|--------------------|--------------------------|
| Irradiance ⁽¹⁾ | H | | | | mW/cm ² | I _F =20 mA |
| SEP8506-001 | | 0.05 | 0.36 | | | |
| SEP8506-002 | | 0.33 | 0.52 | | | |
| SEP8506-003 | | 0.45 | 0.90 | | | |
| Forward Voltage | V _F | | 1.5 | | V | I _F =20 mA |
| Reverse Breakdown Voltage | V _{BR} | 3.0 | | | V | I _R =10 µA |
| Peak Output Wavelength | λ _P | 935 | | | nm | |
| Spectral Bandwidth | Δλ | 50 | | | nm | |
| Spectral Shift With Temperature | Δλ _P /ΔT | 0.3 | | | nm/°C | |
| Beam Angle ⁽²⁾ | Ø | 50 | | | degr. | I _F =Constant |
| Radiation Rise And Fall Time | t _r , t _f | 0.7 | | | µs | |

Notes

1. Measured in mW/cm² into a 0.104 (2.64) diameter aperture placed 0.535 (13.6) from the lens tip.
2. Beam angle is defined as the total included angle between the half intensity points.

ABSOLUTE MAXIMUM RATINGS

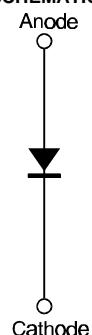
(25°C Free-Air Temperature unless otherwise noted)

| | |
|-------------------------------|-----------------------|
| Continuous Forward Current | 50 mA |
| Power Dissipation | 100 mW ⁽¹⁾ |
| Storage Temperature Range | -40°C to 85°C |
| Operating Temperature Range | -40°C to 85°C |
| Soldering Temperature (5 sec) | 240°C |

Notes

1. Derate linearly from 25°C free-air temperature at the rate of 0.78 mW/°C.

SCHEMATIC



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

Honeywell

SEP8506

GaAs Infrared Emitting Diode

Fig. 1 Radiant Intensity vs Angular Displacement gra_030.ds4

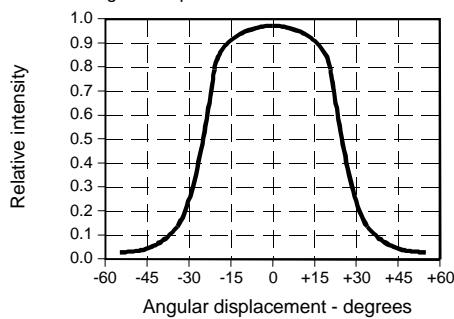


Fig. 2 Radiant Intensity vs Forward Current gra_028.ds4

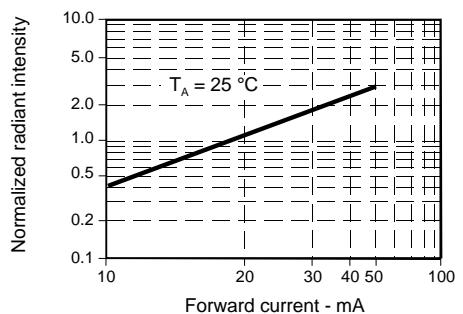


Fig. 3 Forward Voltage vs Forward Current gra_003.ds4

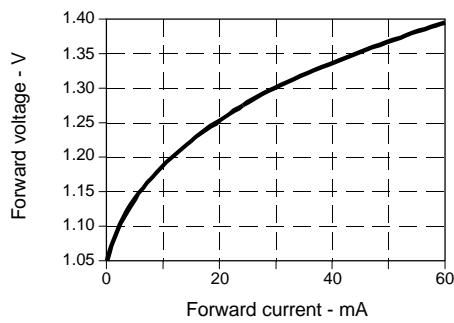


Fig. 4 Forward Voltage vs Temperature gra_207.ds4

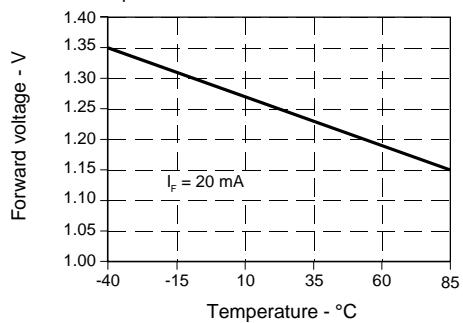


Fig. 5 Spectral Bandwidth gra_005.ds4

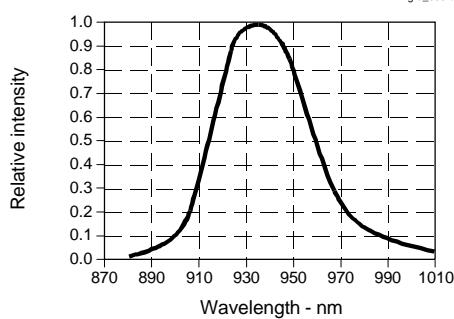
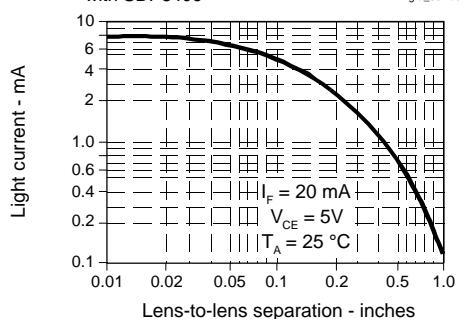
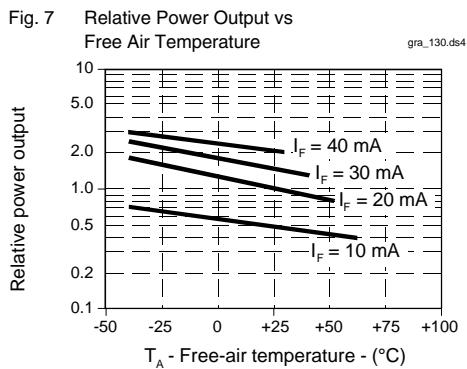


Fig. 6 Coupling Characteristics with SDP8406 gra_031.ds4



SEP8506

GaAs Infrared Emitting Diode



All Performance Curves Show Typical Values

Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

Honeywell

43